

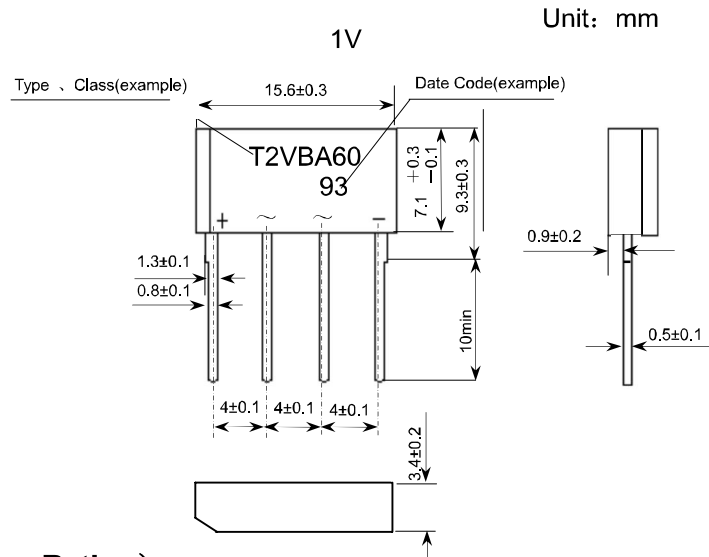
■ Features

- I_o 1.5A
- V_{RRM} 200V~800V
- Glass passivated chip
- High surge forward current capability
- Small size

■ Applications

- General purpose 1 phase Bridge rectifier applications

Outline Dimensions and Mark



■ Limiting Values (Absolute Maximum Rating)

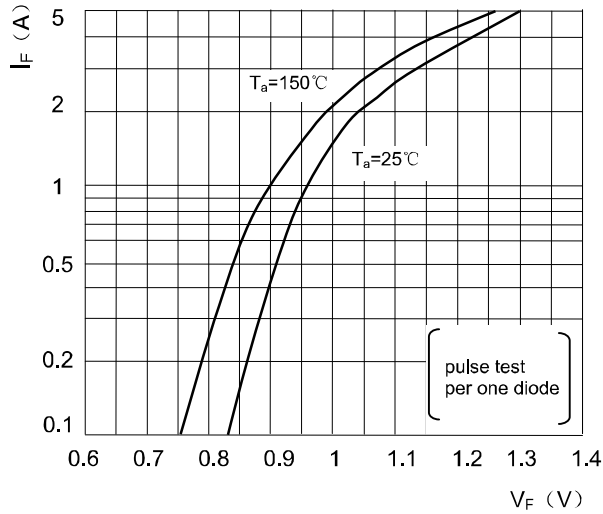
Item	Symbol	Unit	Conditions	T2VBA20	T2VBA40	T2VBA60	T2VBA80
Storage Temperature	T_{stg}	°C		-40 ~ +150			
Junction Temperature	T_j	°C		+150			
Repetitive Peak Reverse Voltage	V_{RRM}	V		200	400	600	800
Average Rectified Output Current	I_o	A	50Hz sine wave, R-load, $T_a=25^{\circ}\text{C}$	1.5			
Surge(Non-repetitive)Forward Current	I_{FSM}	A	50Hz sine wave, 1 cycle, $T_a=25^{\circ}\text{C}$	50			
Current Squared Time	I^2t	A ² s	1ms≤t<8.3ms $T_j=25^{\circ}\text{C}$, Rating of per diode	10			



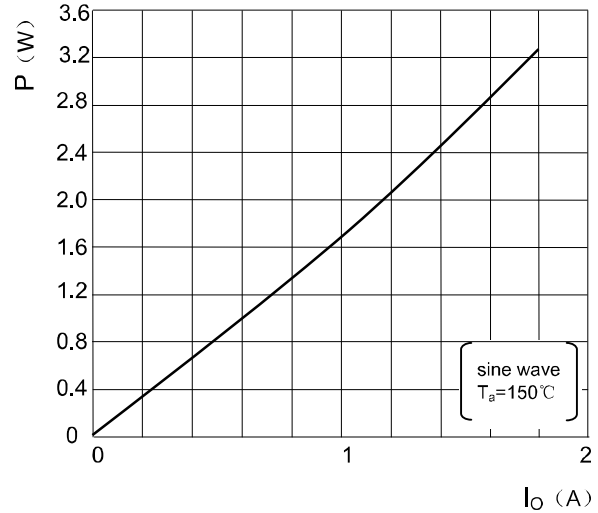
Electrical Characteristics ($T_a=25^{\circ}\text{C}$ Unless otherwise specified)

Item	Symbol	Unit	Test Condition	Max
Peak Forward Voltage	V_{FM}	V	$I_{FM}=0.75\text{A}$, Pulse measurement, Rating of per diode	0.98
Peak Reverse Current	I_{RRM1}	μA	$V_{RM}=V_{RRM}$, Pulse measurement, Rating of per diode	10
Thermal Resistance	$R_{\theta J-A}$	°C/W	Between junction and ambient	62
	$R_{\theta J-L}$		Between junction and lead	16

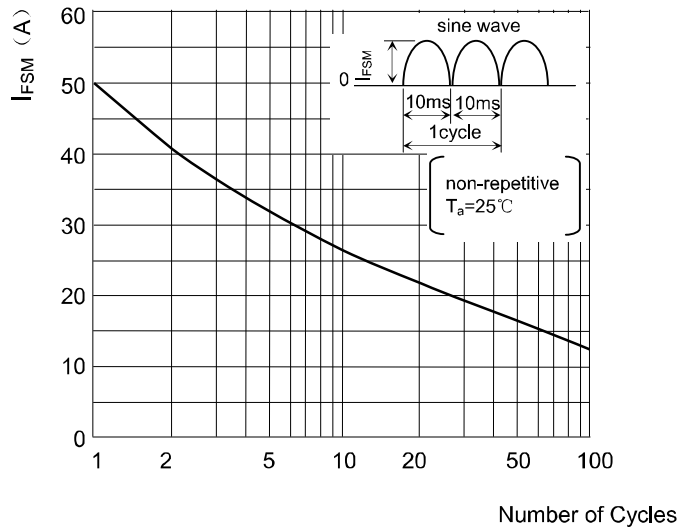
■ Characteristics(Typical)



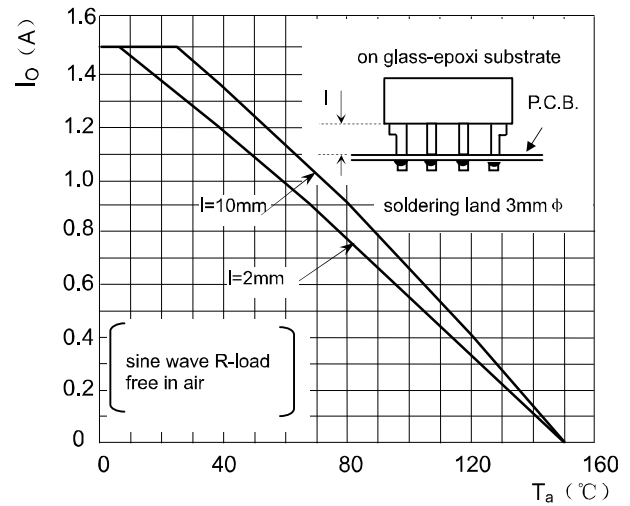
Forward Characteristics



P- I_O Curve



Surge Forward Current Capability



I_O - T_a Curve